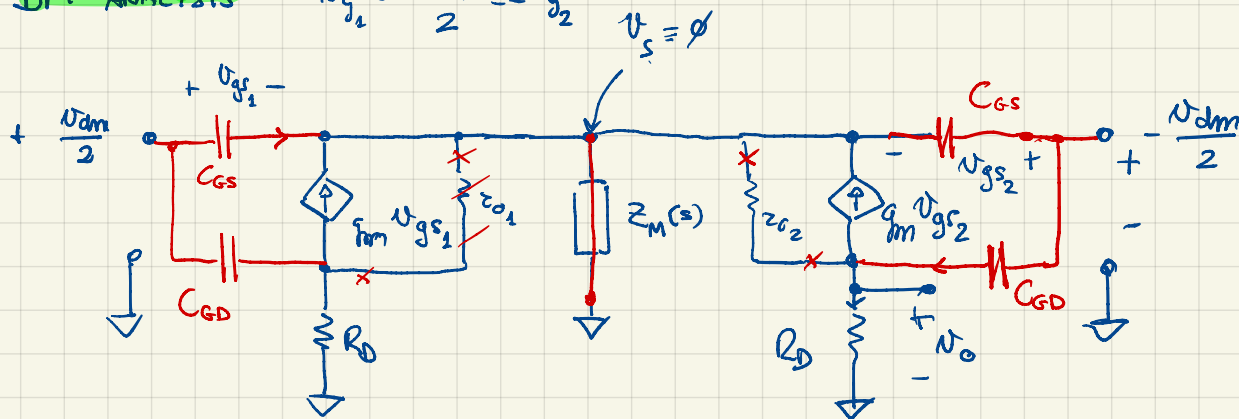


DM ANALYSIS

$$U_{gs1} = \frac{U_{dm}}{2} = -U_{gs2}$$



$$g_{m1} = g_{m2} = g_m \quad z_{o1} = z_{o2} = z_o \quad \text{NEGLECTIBLE}$$

LET'S CALCULATE THE SOURCE VOLTAGE U_s

$$\begin{aligned} U_s &= Z_M(s) \cdot (sC_{gs} \cdot U_{gs1} + g_m U_{gs1} + sC_{gs} U_{gs2} + g_m U_{gs2}) = \\ &= Z_M(s) \cdot (sC_{gs} + g_m) (U_{gs1} + U_{gs2}) = -Z_M(s) (g_m + sC_{gs}) \cdot 2U_s \end{aligned}$$

$$U_{gs1} = \frac{U_{dm}}{2} - U_s; \quad U_{gs2} = -\frac{U_{dm}}{2} - U_s \Rightarrow U_{gs1} + U_{gs2} = -2U_s$$

THE EQUATION FOR U_s IS HOMOGENEOUS \Rightarrow

$$U_s = -Z_M(s) (sC_{gs} + g_m) 2U_s \Leftrightarrow U_s \equiv 0 !!$$

CONCLUSION: THE DM CIRCUIT IS COMMON SOURCE TYPE AND ITS GAIN DOES NOT DEPEND ON THE CURRENT MIRROR CHARACTERISTICS

LET'S NOW FIND THE DM GAIN

$$U_o = R_D \left[sC_{GD} \left(-\frac{U_{dm}}{2} - U_o \right) - g_m U_{gs2} \right] = -R_D \left[sC_{GD} \left(+\frac{U_{dm}}{2} + U_o \right) - g_m \frac{U_{dm}}{2} \right]$$

$$U_o = \frac{U_{dm}}{2} \frac{g_m R_D - sC_{GD} R_D}{1 + sC_{GD} R_D} = \frac{U_{dm}}{2} \cdot g_m R_D \cdot \frac{1 - s \frac{C_{GD}}{g_m}}{1 + sC_{GD} R_D}$$

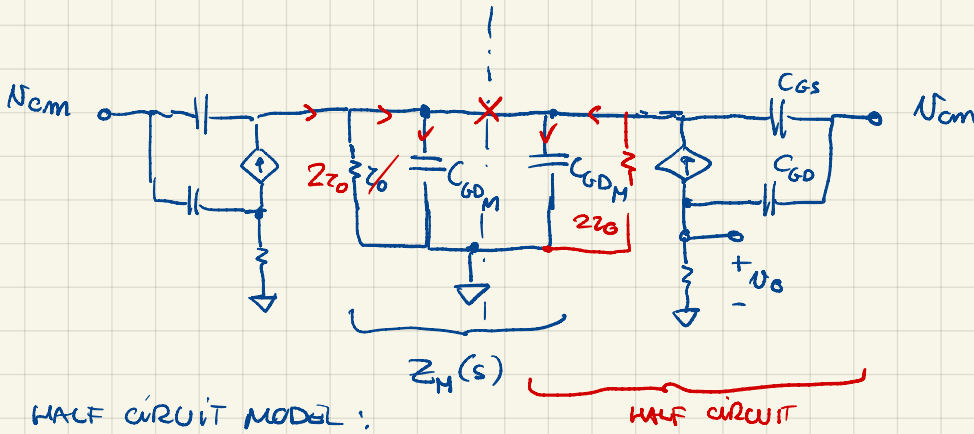
$$A_{dm} \triangleq \frac{U_o}{U_{dm}} = \frac{g_m R_D}{2} \cdot \frac{1 - s \frac{C_{GD}}{g_m}}{1 + sC_{GD} R_D} \leftarrow \text{HIGH FREQUENCY ZERO}$$

$$\lim_{s \rightarrow +\infty} A_{dm}(s) = -\frac{1}{2} \quad (\text{OBVIOUS FROM CIRCUIT INSPECTION!})$$

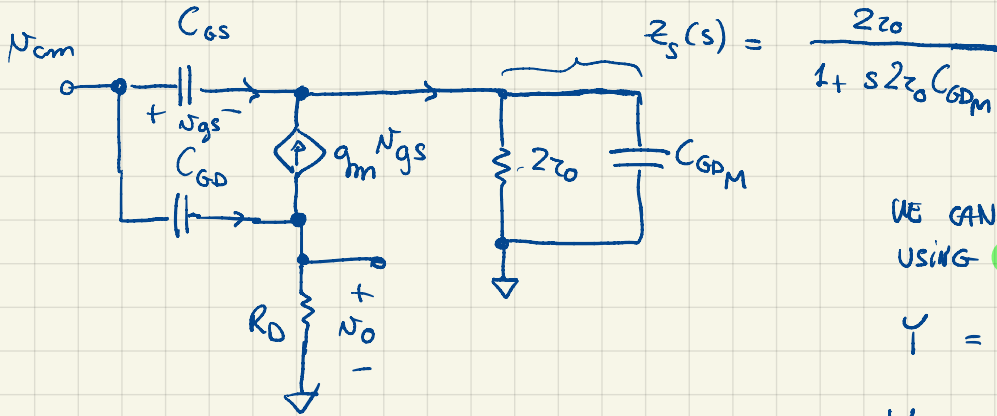
CM ANALYSIS

WE USE THE HALF-CIRCUIT MODEL

$$V_{g1} = V_{g2} = V_{cm}$$



HALF CIRCUIT MODEL:



WE CAN SIMPLIFY THIS CIRCUIT USING MILLER'S THEOREM

$$Y = s C_{GD}$$

$$Y_1 = Y(1 - G)$$

$$Y_2 = Y\left(1 - \frac{1}{G}\right)$$

$$G = A_{21} = \frac{V_o}{V_{cm}} \text{ IN OUR CASE}$$

G IS APPROXIMATELY KNOWN IF WE CONSIDER ITS MIDBAND VALUE.

$$G_{MB} = \frac{V_o}{V_{cm}} \approx - \frac{g_m R_D}{1 + g_m 2z_o} \approx - \frac{R_D}{2z_o}$$

NEGLIGIBLE

VERY SMALL GAIN $\propto 10^{-2}$

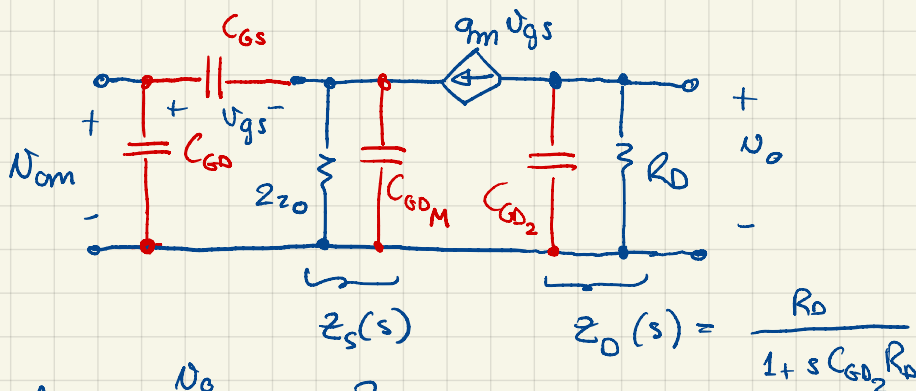
AS A RESULT

$$Y_1 \approx Y = s C_{GD}$$

$$Y_2 \approx s C_{GD} \cdot \left(1 + \frac{2z_o}{R_D}\right) \approx 10^2 C_{GD}$$

C_{GD2}

NOW WE CAN RE-DRAW THE CIRCUIT



FROM CIRCUIT INSPECTION WE EXPECT TWO POLES AND A ZERO

$$A_{cm} = \frac{V_o}{V_{cm}} = ?$$

$$\begin{cases} U_o = -Z_D(s) \cdot g_m U_{gs} \\ U_{gs} = U_{cm} - Z_s(s) \cdot (sC_{GS} U_{gs} + g_m U_{gs}) \end{cases}$$

$$\begin{cases} U_{gs} = \frac{U_{cm}}{1 + Z_s(s)(sC_{GS} + g_m)} \\ U_o = -U_{cm} \cdot \frac{g_m Z_D(s)}{1 + (g_m + sC_{GS})Z_s(s)} \end{cases}$$

$$A_{cm} = \frac{U_o}{U_{cm}} = - \frac{\frac{g_m R_D}{1 + sC_{GD2} R_D}}{1 + (g_m + sC_{GS}) \cdot \frac{2z_o}{1 + s2z_o C_{GDM}}} = - \frac{g_m R_D (1 + s2z_o C_{GDM})}{(1 + sC_{GD2} R_D) [1 + 2g_m z_o + s2z_o (C_{GDM} + C_{GS})]}$$

$\frac{1}{\omega_{p1}}$

$$A_{cm} \triangleq \frac{U_o}{U_{cm}} = - \underbrace{\frac{g_m R_D}{1 + 2g_m z_o}}_{G_{MB}} \cdot \frac{1 + 2z_o C_{GDM} s}{(1 + sC_{GD2} R_D) \left[1 + s \frac{2z_o (C_{GDM} + C_{GS})}{1 + 2z_o g_m} \right]}$$

$\frac{1}{\omega_{p1}}$ MIDBAND FREQUENCY $\frac{1}{\omega_{p2}}$ → RELATIVELY HIGH FREQUENCY

$$\omega_z = \frac{1}{2z_o C_{GDM}} \quad \text{VERY LOW FREQUENCY} \quad \propto 10^3 \text{ Hz}$$

THIS ZERO LIMITS THE CMRR = $\frac{A_{dm}}{A_{cm}}$ BANDWIDTH!

REMARK: WE HAVE FOUND THESE RESULTS USING MILLER'S THEOREM. ARE THEY MEANINGFUL?

THEY ARE AS LONG AS $A_{cm} \approx G_{MB}$, WHICH MEANS UP TO THE ZERO FREQUENCY.

EXERCISE 1

Consider the amplifier in the figure below, whose parameters are (@ $T = 25^\circ\text{C}$):

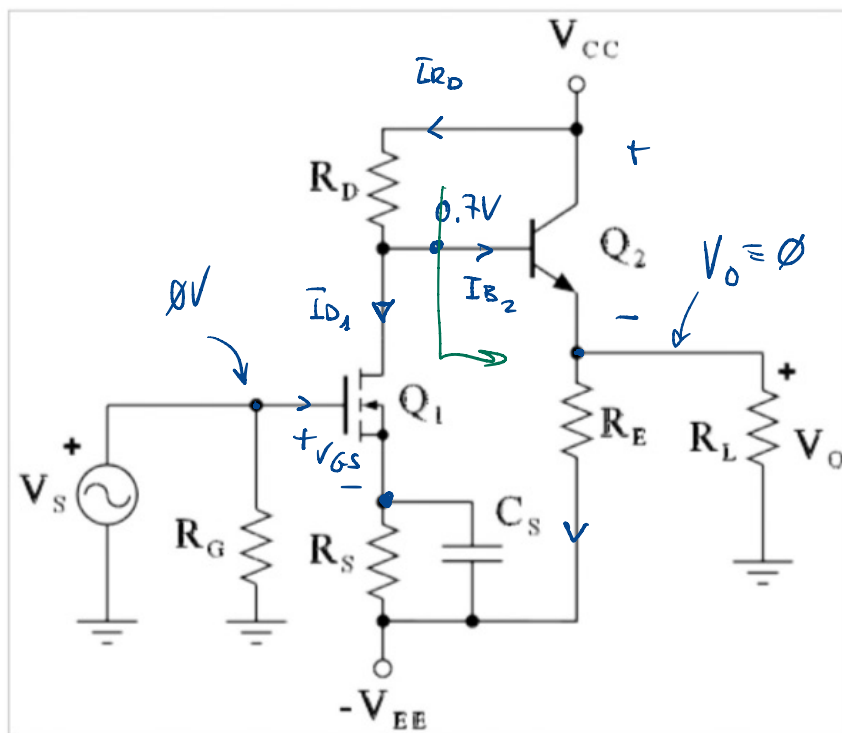
$$V_{CC} = V_{EE} = 30\text{V}, R_G = 500\text{k}\Omega, R_D = 15\text{k}\Omega, R_E = 5\text{k}\Omega, R_L = 7.5\text{k}\Omega$$

MOSFET: $V_T = 8\text{V}, I_{DSS} = V_T^2 k_W/L = 8\text{mA}, r_d = \infty. \quad I_D = I_{DSS} \left(1 - \frac{V_{GS}}{V_T}\right)^2$

BJT: $V_{BE} = 0.7\text{V}, \beta_F = 150, \beta_0 = 200, r_o = \infty.$

Determine:

- 1) I_{CQ}, I_{DQ} and R_S so that $V_O = 0\text{V}$.
- 2) Voltage gain at low frequency, $A_{V1} = v_o/v_s$ considering C_S open.
- 3) Voltage gain (mid frequency) $A_{V2} = v_o/v_s$ considering C_S shorted.
- 4) Low frequency cut-off f_L due to $C_S = 100\mu\text{F}$.
- 5) Draw the Bode asymptotic diagram of $A_V(f)$.



BIAS POINT ANALYSIS

$$V_O \equiv 0\text{V} \Rightarrow V_{R_E} = V_{EE} \quad I_{E_2} \approx \frac{V_{EE}}{R_E} = 6\text{mA} \Rightarrow I_{C_2}, I_{B_2}$$

$$V_{CE_2} = V_{CC} = 30\text{V} \Rightarrow \text{F.A.R.} \quad \checkmark$$

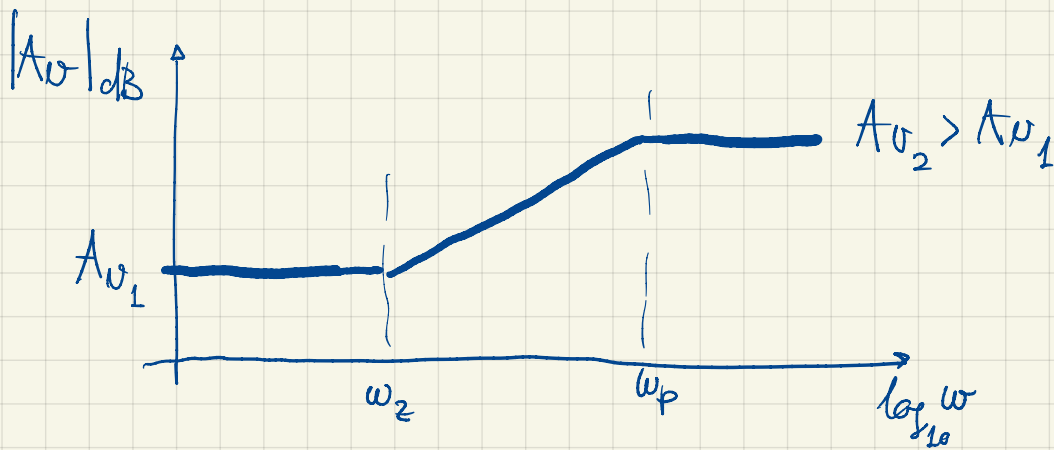
$$I_{D_1} = I_{R_D} - I_{B_2} = \frac{V_{CC} - V_{BE}}{R_D} - I_{B_2} \approx 2\text{mA} \Rightarrow V_{GS_1} > V_T$$

$$V_{R_S} = V_{GS} - V_{EE} \quad I_{R_S} = I_{D_1} \Rightarrow R_S = \frac{V_{R_S}}{I_{D_1}}$$

$$A_{v1} = \frac{v_o}{v_s} = - \frac{g_{m1} R_D \parallel R_{in2}}{1 + g_{m1} R_S} \cdot \frac{(\beta_0 + 1) R_E \parallel R_L}{R_{in2}} \quad C_S = \text{"OPEN"}$$

$$R_{in2} = Z_{i2} + R_E \parallel R_L (\beta_0 + 1)$$

$$A_{v2} = - g_{m1} R_D \parallel R_{in2} \cdot \frac{(\beta_0 + 1) R_E \parallel R_L}{R_{in2}} \quad C_S = \text{"SHORT"}$$



$$\omega_p = \frac{1}{R_{CS} C_S}, \quad R_{CS} = R_S \parallel \frac{1}{g_{m1}}$$

EXERCISE 2

Consider the amplifier in the figure, whose parameters @ $T = 25^\circ\text{C}$ are the following:

$$V_{CC} = 36\text{V}; R_5 = 10\text{k}\Omega$$

$$Q1: \beta_{F1} = 100; \beta_{O1} = 200, I_{C1} = -0.4\text{mA}; V_{CE1} = -16\text{V}, V_{BE} = -0.7\text{V} (r_o = \infty)$$

$$Q2: \beta_{F2} = 100; \beta_{O2} = 200, I_{C2} = 2\text{mA}; V_{CE2} = 18\text{V}, V_{BE} = 0.7\text{V} (r_o = \infty)$$

Determine:

- 1) Resistances R_1, R_2, R_3, R_4 .
- 2) $A_V = v_o/v_s$ (considering C_1 e C_2 shorted and C_x open).
- 3) Resistance R_{iN} indicated in the figure (as per point 2).
- 4) Resistenza R_{oUT} indicated in the figure (as per point 2).
- 5) High frequency cut-off f_H considering only C_x ($C_x = 20\text{pF}$).

